## Journal of Semiconductors

Volume 35 Number 12 December 2014

	SEMICONDUCTOR PHYSICS
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124008	Waveguide-type optical passive ring resonator gyro using frequency modulation spectroscopy technique (4 pages)  Ning Liang, Guo Lijun, Kong Mei, and Chen Tuoyuan
	SEMICONDUCTOR INTEGRATED CIRCUITS
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Anjana R and Ajay Somkuwar

125001

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125013	IC design of low power, wide tuning range VCO in 90 nm CMOS technology (6 pages) Li Zhu, Wang Zhigong, Li Zhiqun, Li Qin, and Liu Faen
	SEMICONDUCTOR TECHNOLOGY
126001	Reducing the mechanical action of polishing pressure and abrasive during copper chemical mechanical planarization (5 pages)  Jiang Mengting and Liu Yuling
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126003	Mechanism analysis of the affect the copper line surface roughness after FA/O alkaline barrier CMP (5 pages) Gao Jiaojiao, Liu Yuling, Wang Chenwei, and Cui Jin
129501	Annual List of Contents to Volume 35 (16 pages)
129901	Author Index to Volume 35 (20 pages)